

Description

The DC4581D3 is a bi-directional high power TVS diode, utilizing leading monolithic silicon technology to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive data and power line. The DC4581D3 complies with the IEC61000-4-2(ESD) standard with $\pm 30\text{kV}$ air and $\pm 30\text{kV}$ contact discharge. It is assembled into a SOD-323 lead-free package. The small size and high ESD surge protection make DC4581D3 an ideal choice to protect cell phone, digital cameras, audio players and many other portable applications.

Mechanical Characteristics

- ◆ Package: SOD-323
- ◆ Lead Finish: Matte Tin
- ◆ Case Material: "Green" Molding Compound.
- ◆ Moisture Sensitivity: Level 3 per J-STD-020
- ◆ Terminal Connections: See Diagram Below
- ◆ Marking Information: See Below

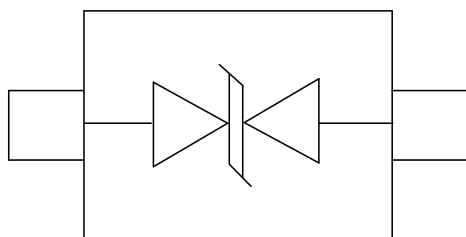
Features

- ◆ Protects one power line or data line
- ◆ High peak pulse current capability
- ◆ Operating voltage: 4.5V
- ◆ Ultra low clamping voltage
- ◆ Complies with following standards:
 - IEC 61000-4-2 (ESD) immunity test
 - Air discharge: $\pm 30\text{kV}$
 - Contact discharge: $\pm 30\text{kV}$
 - IEC61000-4-5 (Lightning) 140A (8/20 μs)
- ◆ RoHS Compliant

Applications

- ◆ Mobile Phones and Accessories
- ◆ Battery Protection
- ◆ Power Supply Protection
- ◆ Hand Held Portable Applications
- ◆ Peripherals

Dimensions and Pin Configuration



Circuit and Pin Schematic

Marking Information



48D = Device Marking Code

Ordering Information

Part Number	Marking	Packaging	Reel Size
DC4581D3	48D	3000/Tape & Reel	7 inch

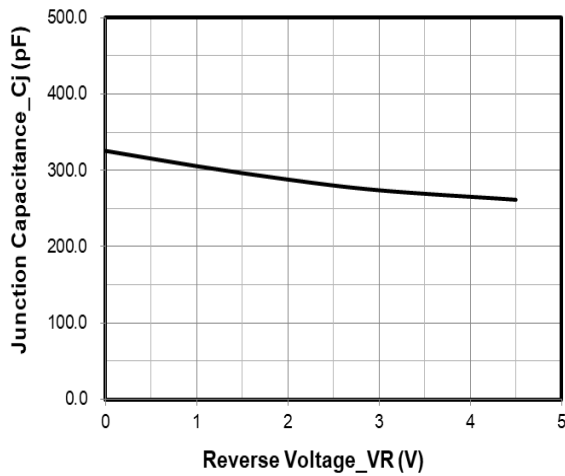
Absolute Maximum Ratings ($T_A=25^{\circ}\text{C}$ unless otherwise specified)

Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20 μs)	Ppk	2400	W
Peak Pulse Current (8/20 μs)	Ipp	140	A
ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	VESD	± 30 ± 30	kV
Operating Temperature Range	TJ	-55 to +125	$^{\circ}\text{C}$
Storage Temperature Range	Tstg	-55 to +150	$^{\circ}\text{C}$

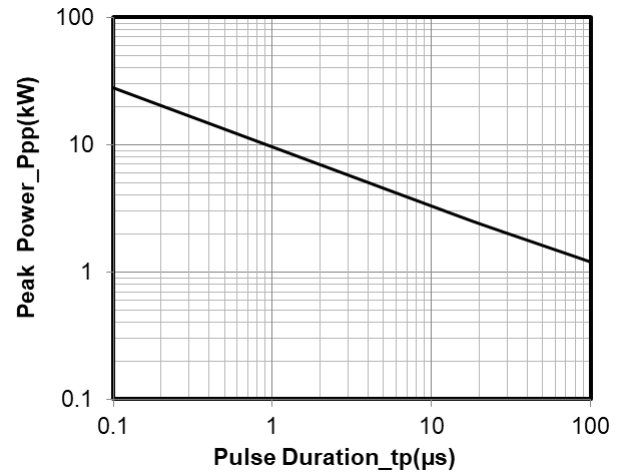
Electrical Characteristics ($T_A=25^{\circ}\text{C}$ unless otherwise specified)

Parameter	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Working Voltage	VRWM			4.5	V	
Breakdown Voltage	VBR	4.7			V	IT = 1mA
Reverse Leakage Current	IR			1.0	μA	VRWM = 4.5V
Clamping Voltage	VC			7.5	V	Ipp = 20A (8 x 20 μs pulse)
Clamping Voltage	VC			17	V	Ipp = 140A (8 x 20 μs pulse)
Junction Capacitance	CJ			300	pF	VR = 0V, f = 1MHz

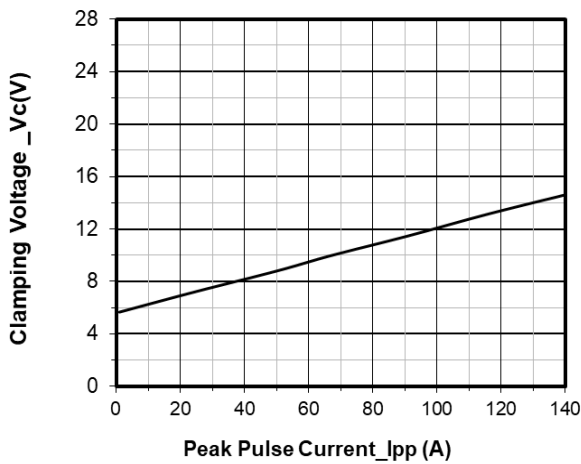
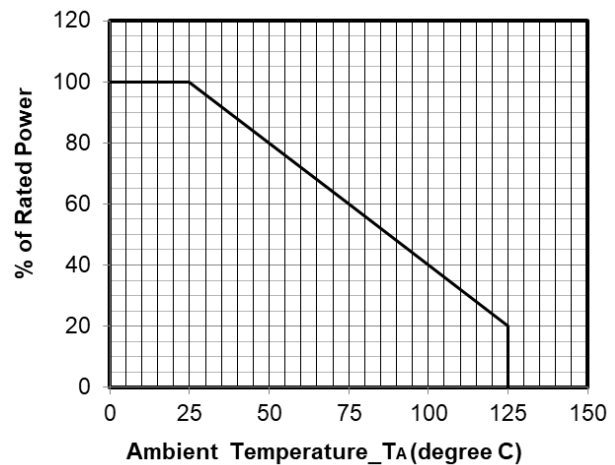
Typical Performance Characteristics (TA=25°C unless otherwise Specified)



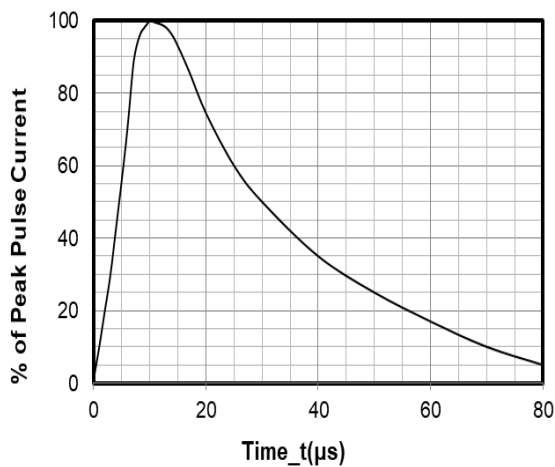
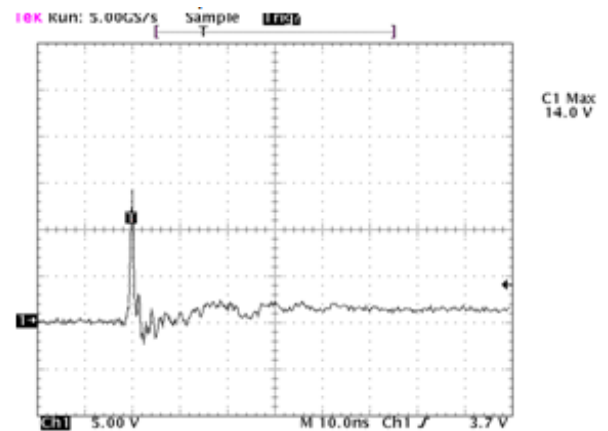
Junction Capacitance vs. Reverse Voltage



Peak Pulse Power vs. Pulse Time


Clamping Voltage vs. Peak Pulse Current ($t_p = 8/20\mu$ s)


Power Derating Curve

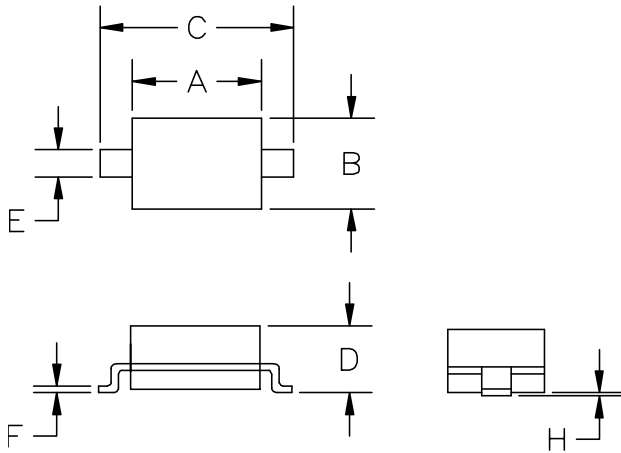

8 X 20 μ s Pulse Waveform


Note: Data is taken with a 10x attenuator

ESD Clamping Voltage

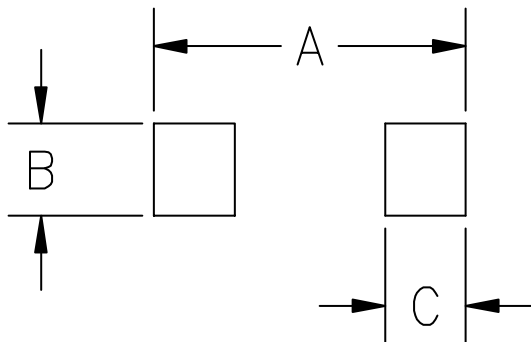
8 kV Contact per IEC61000-4-2

SOD-323 Package Outline Drawing



SYM	DIMENSIONS			
	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	1.50	1.80	0.060	0.071
B	1.20	1.40	0.045	0.054
C	2.30	2.70	0.090	0.107
D	-	1.10	-	0.043
E	0.30	0.40	0.012	0.016
F	0.10	0.25	0.004	0.010
H	-	0.10	-	0.004

Suggested Land Pattern



SYM	DIMENSIONS	
	MILLIMETERS	INCHES
A	3.15	0.120
B	0.80	0.031
C	0.80	0.031

Contact Information

Changzhou D-first Electronics CO.,Ltd.

www.first-electronic.com

Email: yf@first-electronic.cn

Phone: +86 (0519) 88171671